

HIGH CURRENT APPLICATION.

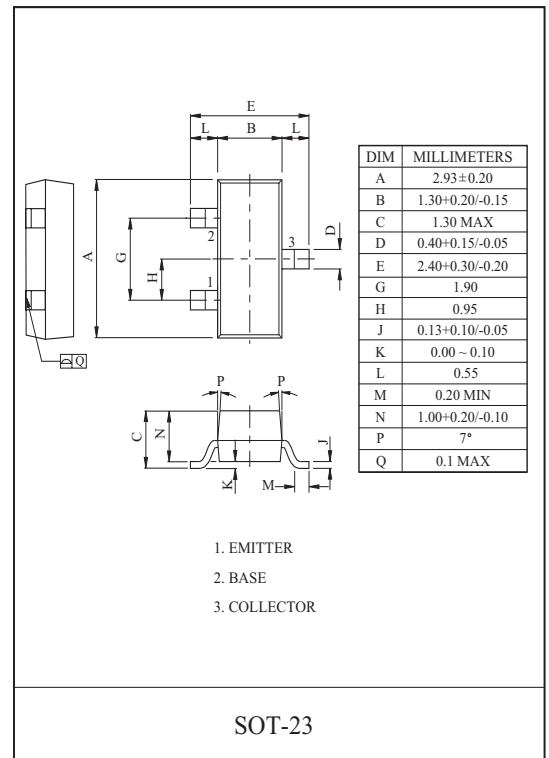
### FEATURE

- Complementary to MPS8550S.
- Suffix U : Qualified to AEC-Q101.  
ex) MPS8050S-RTK/HU

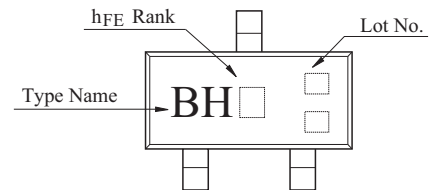
### MAXIMUM RATING (Ta=25 °C)

| CHARACTERISTIC              | SYMBOL    | RATING  | UNIT |
|-----------------------------|-----------|---------|------|
| Collector-Base Voltage      | $V_{CBO}$ | 40      | V    |
| Collector-Emitter Voltage   | $V_{CEO}$ | 25      | V    |
| Emitter-Base Voltage        | $V_{EBO}$ | 6       | V    |
| Collector Current           | $I_C$     | 1.5     | A    |
| Collector Power Dissipation | $P_C^*$   | 350     | mW   |
| Junction Temperature        | $T_j$     | 150     |      |
| Storage Temperature Range   | $T_{stg}$ | -55 150 |      |

\*  $P_C$  : Package Mounted On 99.5% Alumina (10 × 8 × 0.6mm)



### Marking



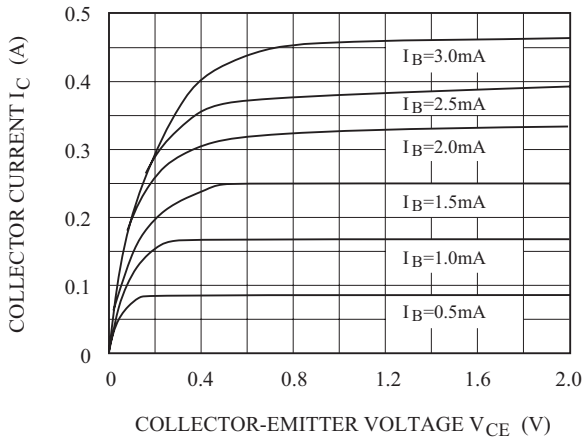
### ELECTRICAL CHARACTERISTICS (Ta=25 °C)

| CHARACTERISTIC                       | SYMBOL             | TEST CONDITION              | MIN. | TYP. | MAX. | UNIT |
|--------------------------------------|--------------------|-----------------------------|------|------|------|------|
| Collector Cut-off Current            | $I_{CBO}$          | $V_{CB}=35V, I_E=0$         | -    | -    | 100  | nA   |
| Emitter Cut-off Current              | $I_{EBO}$          | $V_{EB}=6V, I_C=0$          | -    | -    | 100  | nA   |
| Collector-Base Breakdown Voltage     | $V_{(BR)CBO}$      | $I_C=100 \mu A, I_E=0$      | 40   | -    | -    | V    |
| Collector-Emitter Breakdown Voltage  | $V_{(BR)CEO}$      | $I_C=2mA, I_B=0$            | 25   | -    | -    | V    |
| DC Current Gain                      | $h_{FE(1)}$        | $V_{CE}=1V, I_C=5mA$        | 45   | 135  | -    |      |
|                                      | $h_{FE(2)}$ (Note) | $V_{CE}=1V, I_C=100mA$      | 85   | 160  | 300  |      |
|                                      | $h_{FE(3)}$        | $V_{CE}=1V, I_C=800mA$      | 40   | 110  | -    |      |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$      | $I_C=800mA, I_B=80mA$       | -    | 0.28 | 0.5  | V    |
| Base-Emitter Saturation Voltage      | $V_{BE(sat)}$      | $I_C=800mA, I_B=80mA$       | -    | 0.98 | 1.2  | V    |
| Base-Emitter Voltage                 | $V_{BE}$           | $V_{CE}=1V, I_C=10mA$       | -    | 0.66 | 1.0  | V    |
| Transition Frequency                 | $f_T$              | $V_{CE}=10V, I_C=50mA$      | 100  | 190  | -    | MHz  |
| Collector Output Capacitance         | $C_{ob}$           | $V_{CB}=10V, f=1MHz, I_E=0$ | -    | 9    | -    | pF   |

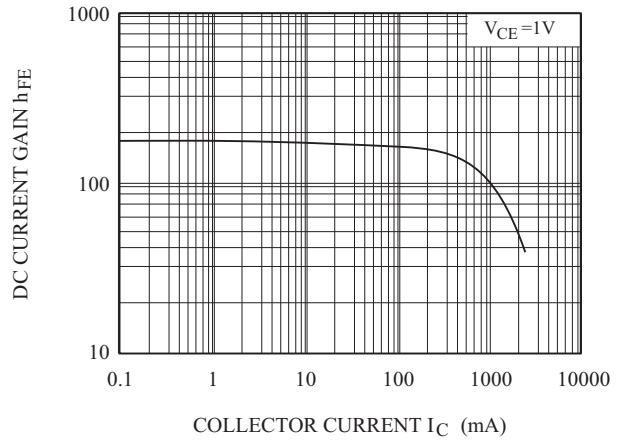
Note :  $h_{FE(2)}$  Classification B:85 160 , C: 120 200 , D: 160 300

# MPS8050S

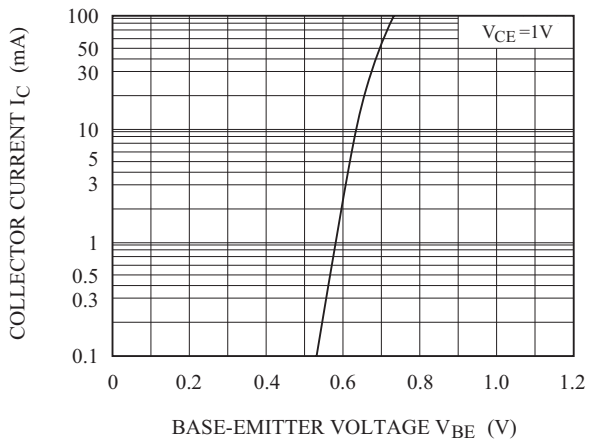
$I_C - V_{CE}$



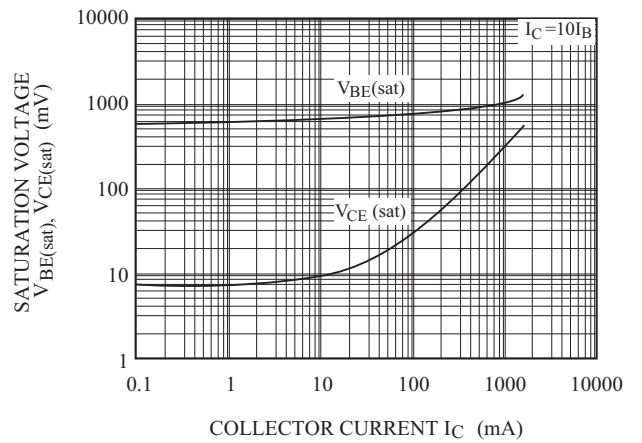
$h_{FE} - I_C$



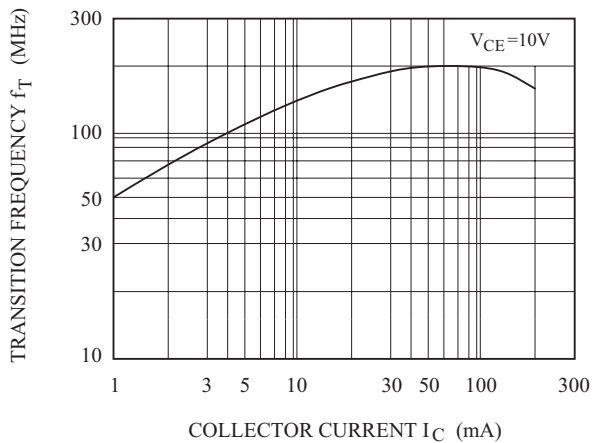
$I_C - V_{BE}$



$V_{BE(sat)}, V_{CE(sat)} - I_C$



$f_T - I_C$



$C_{ob} - V_{CB}$

